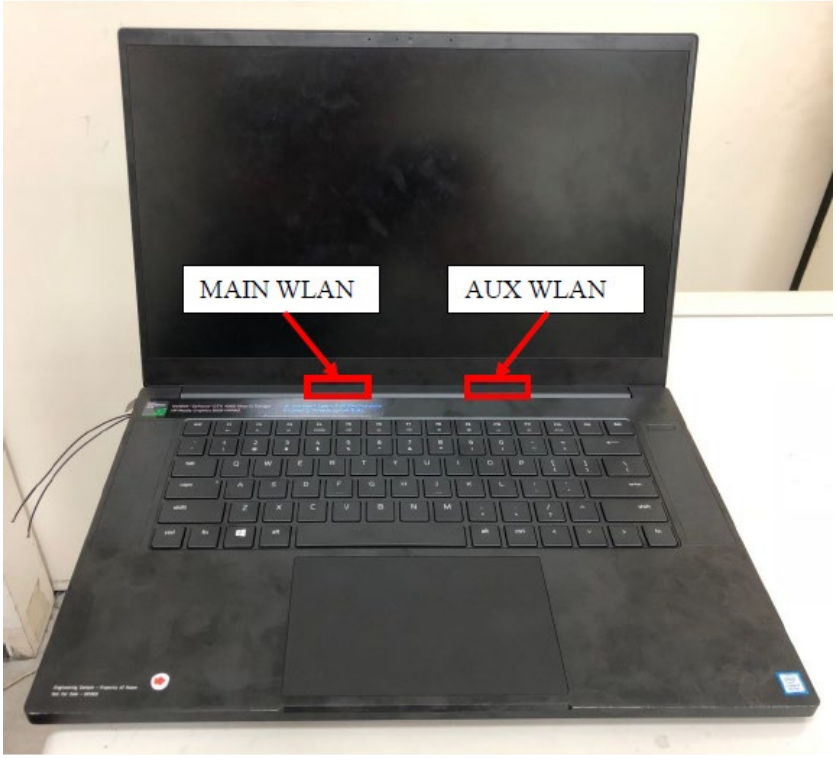
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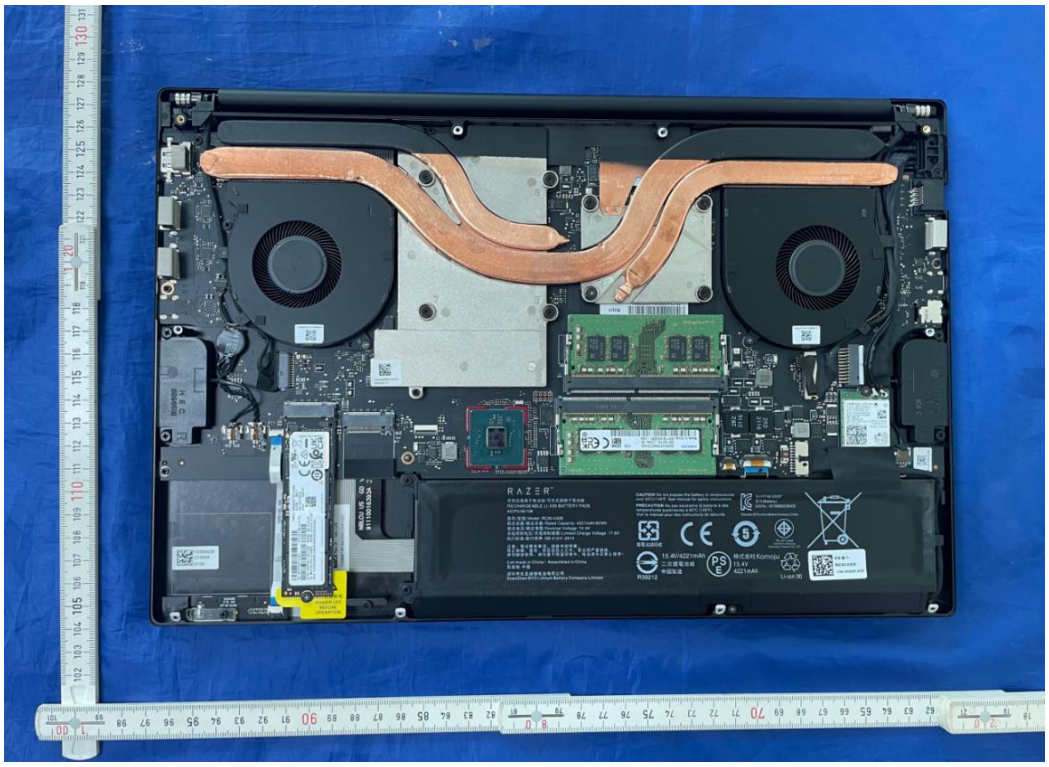

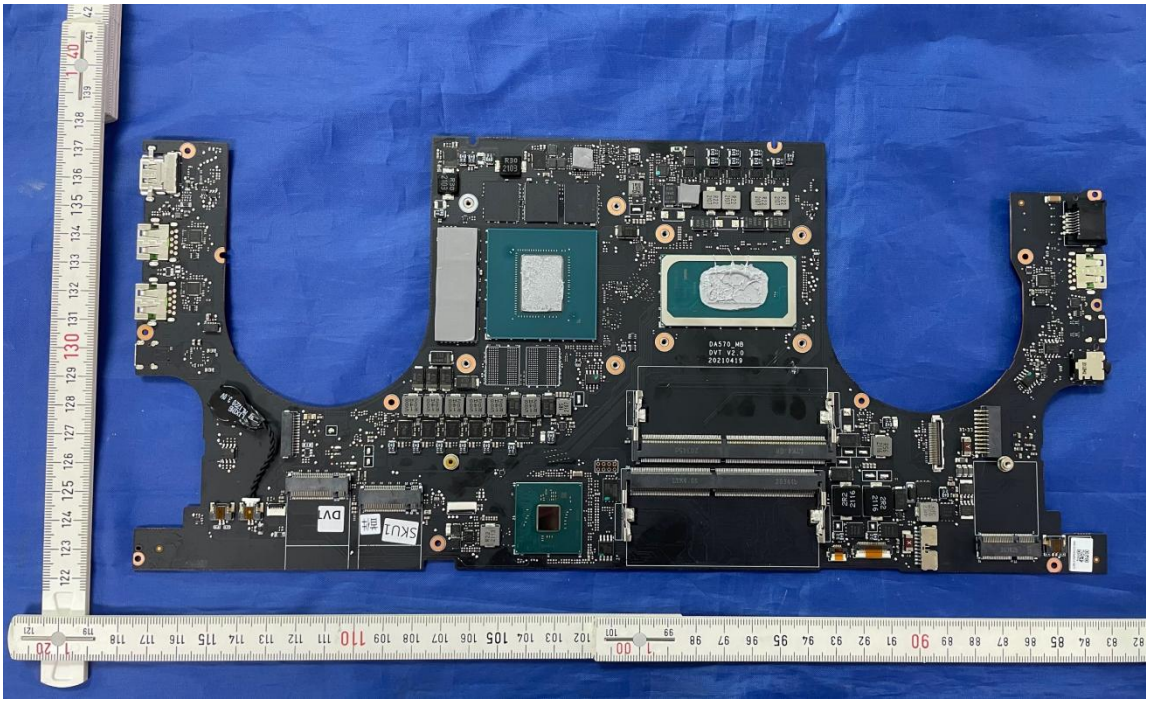
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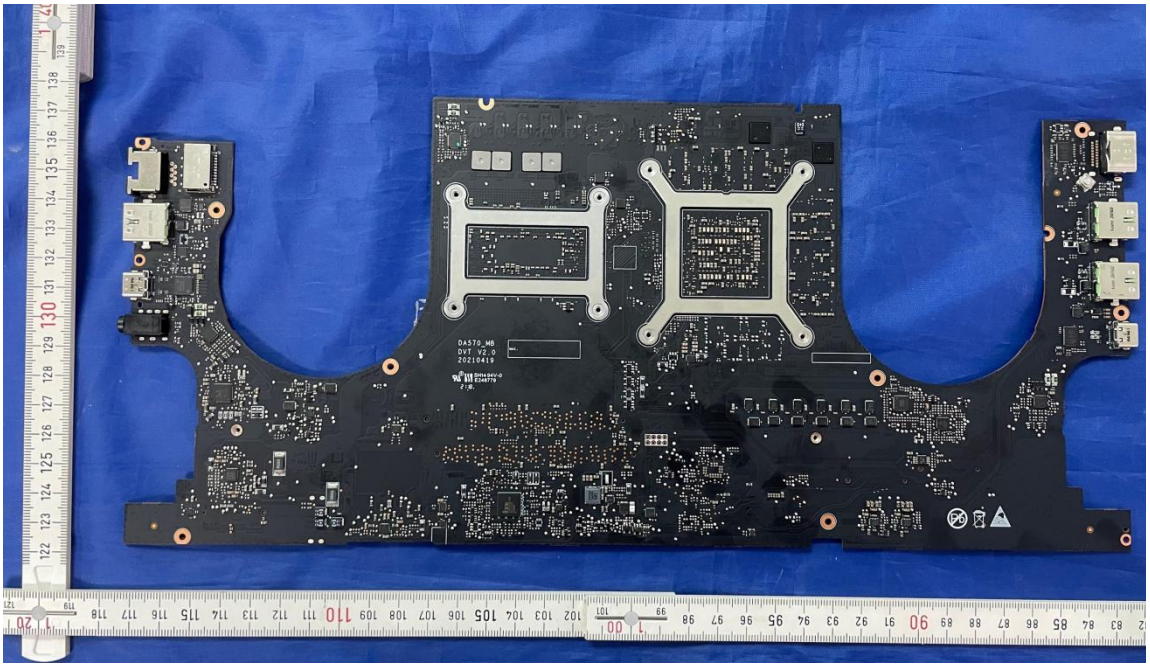
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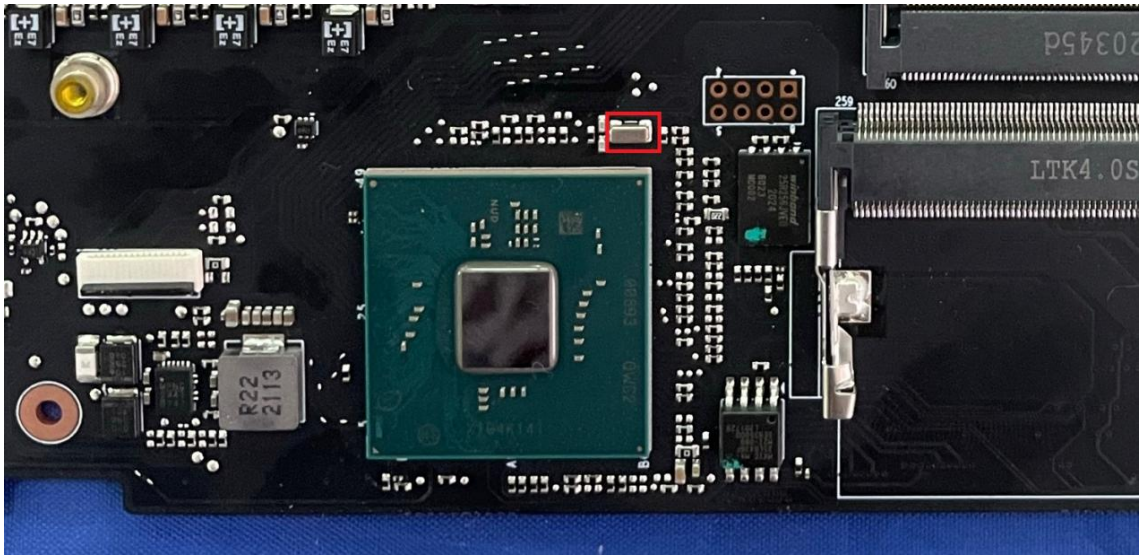
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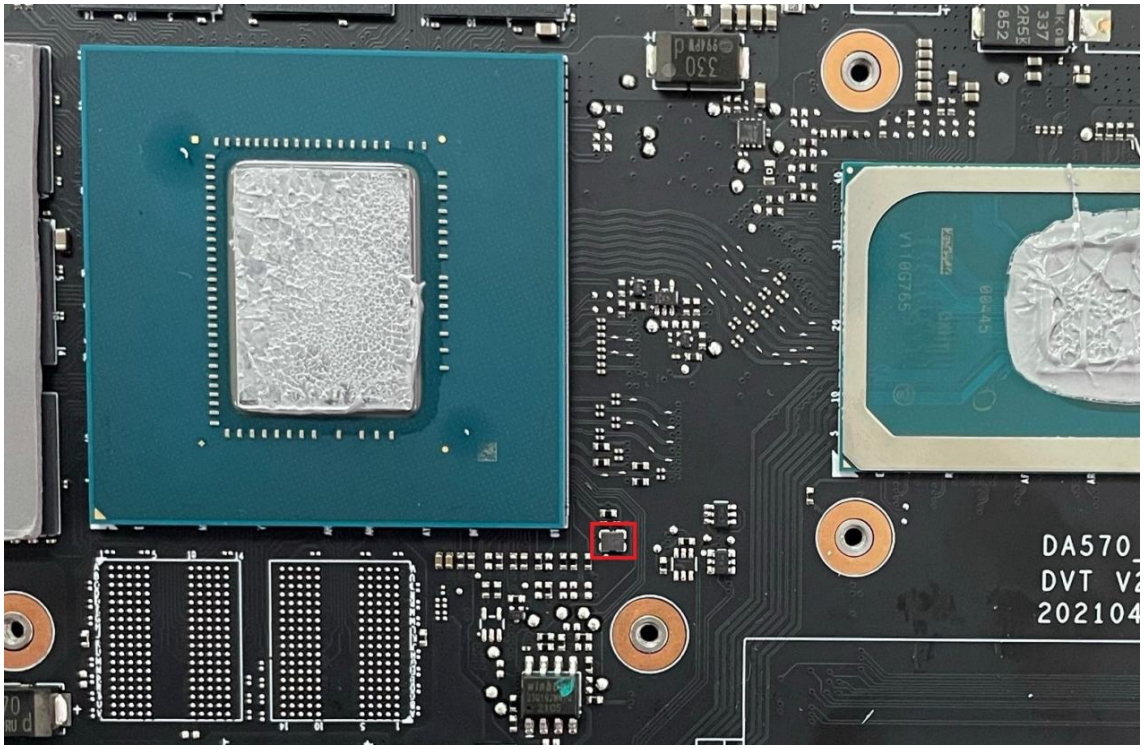
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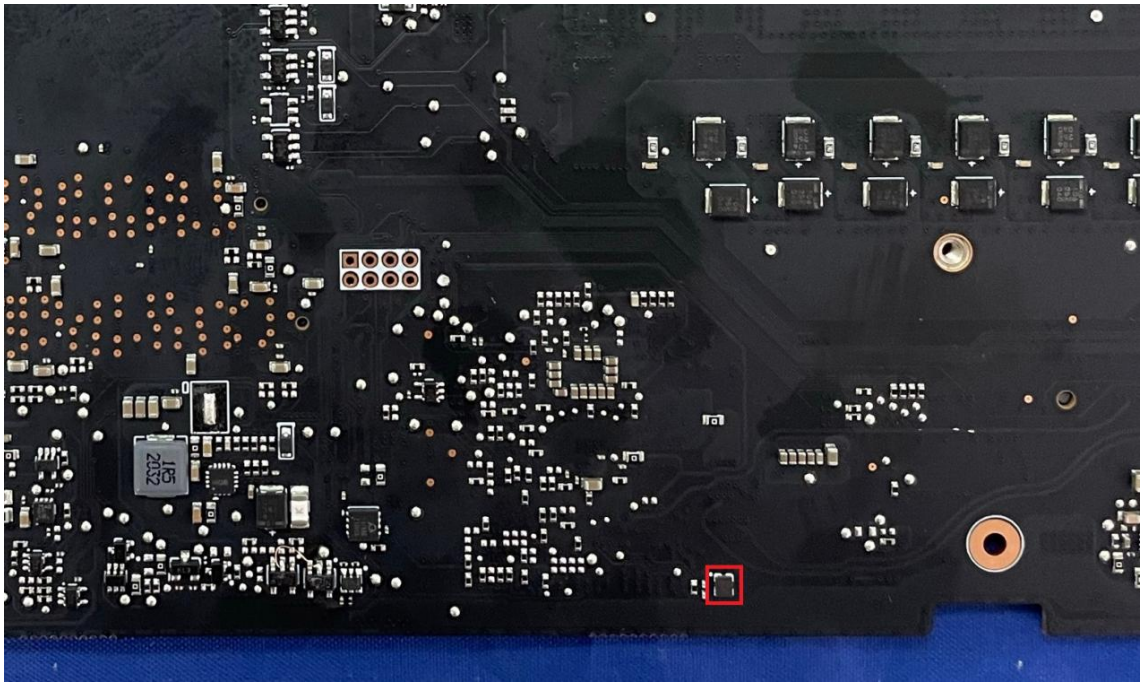

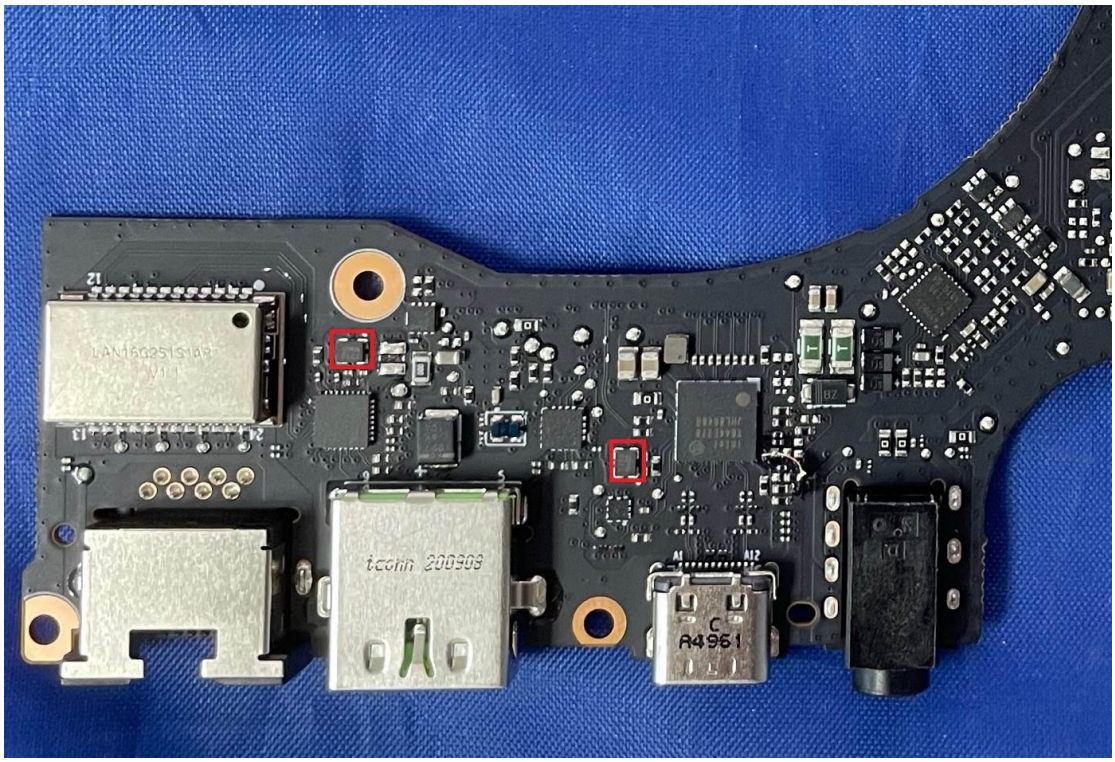
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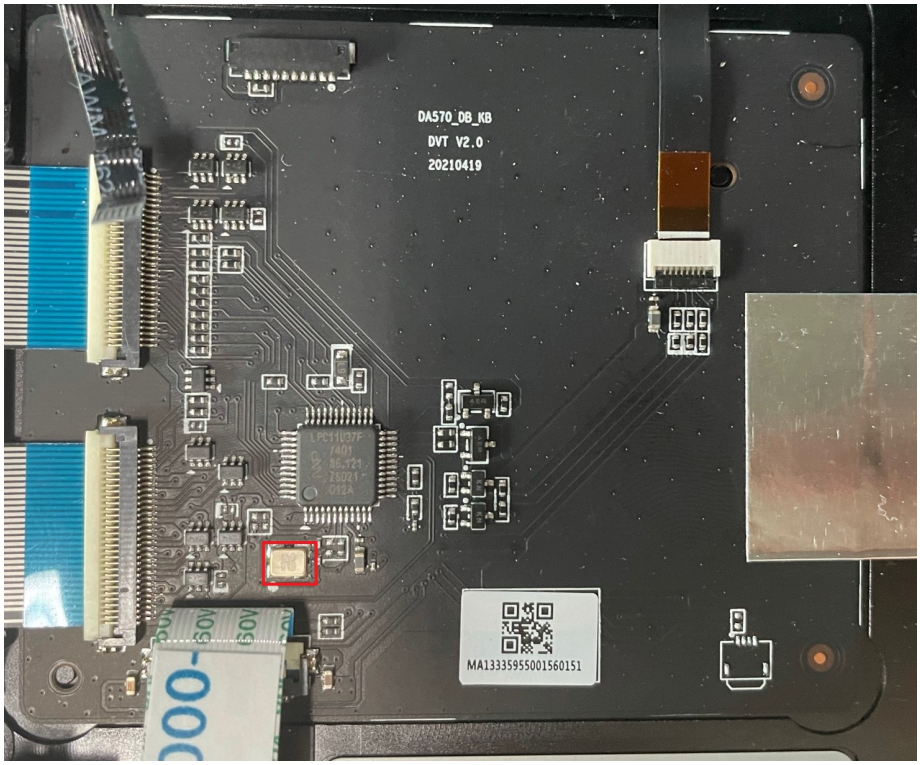
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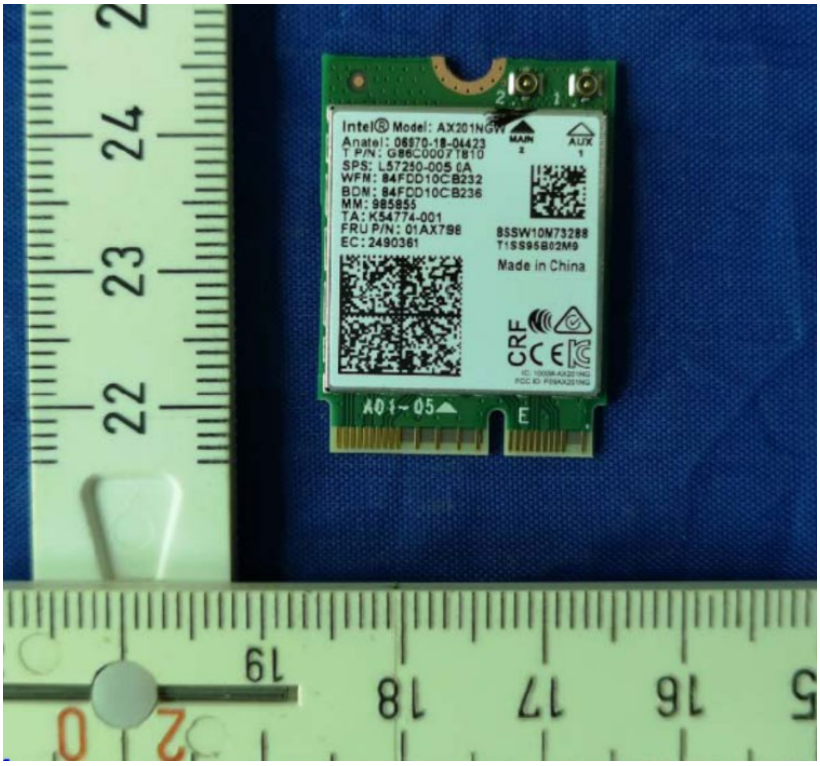
RAZER

RAZER™
可充式锂离子电池组/可充式鋰離子電池組
RECHARGEABLE LI-ION BATTERY PACK
4ICP5/46/108
型号/型號/Model: RC30-0328
額定容量/額定容量/Rated Capacity: 4221mAh/65Wh
額定电压/額定電壓/Nominal Voltage: 15.4V
充电限制电压/充電限制電壓/Limited Charge Voltage: 17.6V
执行标准/執行標準: GB 31241-2014
注意：電池警告事項，請參考說明書。
禁止拆解，撞击，挤压或投入火中。若出现严重鼓胀，
请勿继续使用。请勿置于高温环境中，电池浸水后禁止使用！
Cell made in China / Assembled in China
製造地: 中國
深圳市比亚迪锂电池有限公司
ShenZhen BYD Lithium Battery Company Limited.
CAUTION Do not expose the battery to temperatures over 65°C/149°F. See manual for safety instructions.
PRÉCAUTION Ne pas soumettre la batterie à des températures supérieures à 65°C (149°F). Voir le manuel pour des instructions de sécurité.
廢電池請回收
15.4V/4221mAh
二次鋰電池組
中國製造
R39212

NVIDIA
QUAL SAMPLE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MM: 985855
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A01~05
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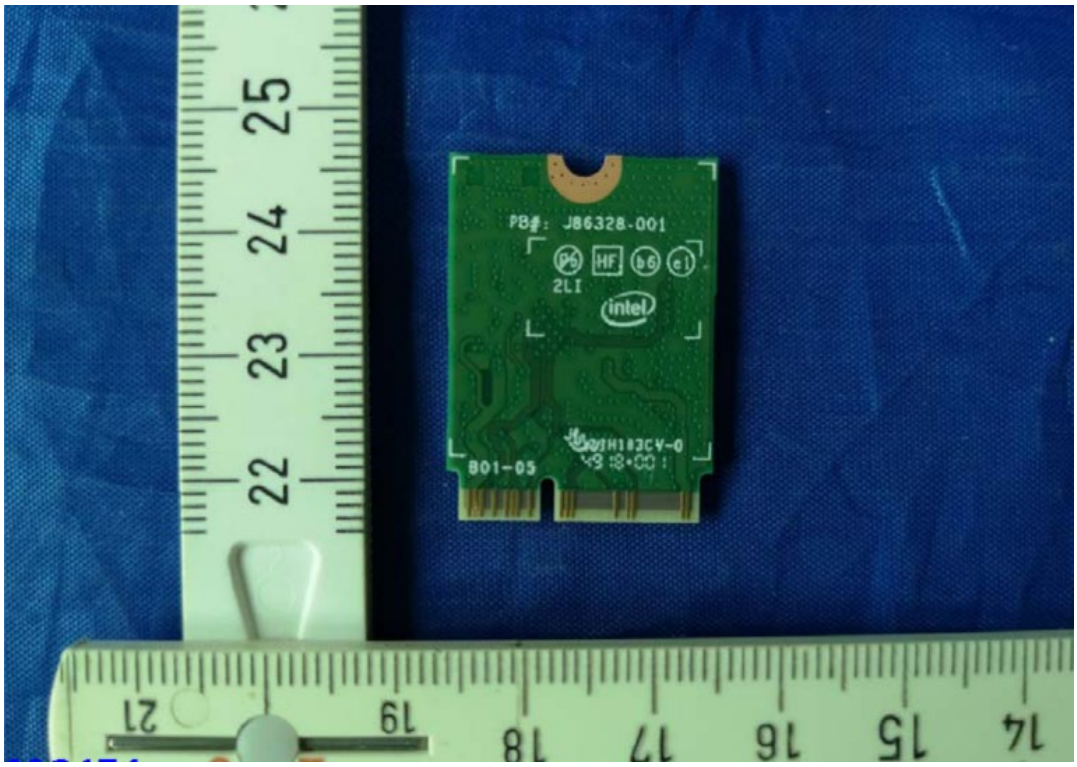
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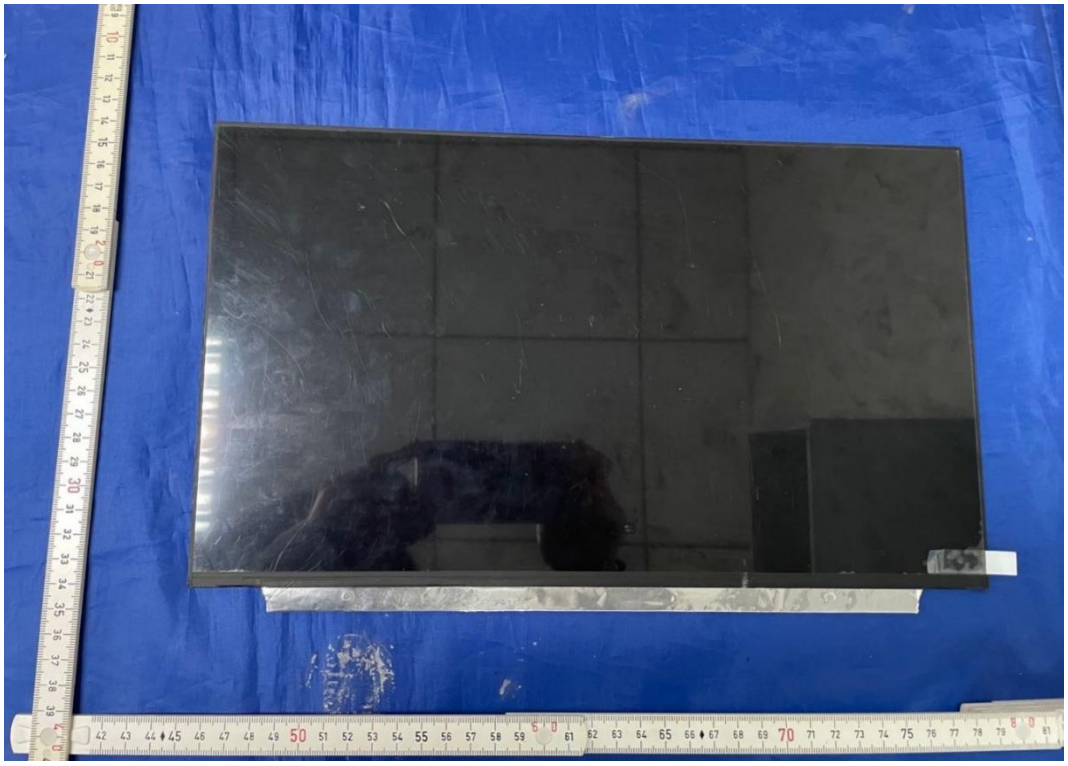

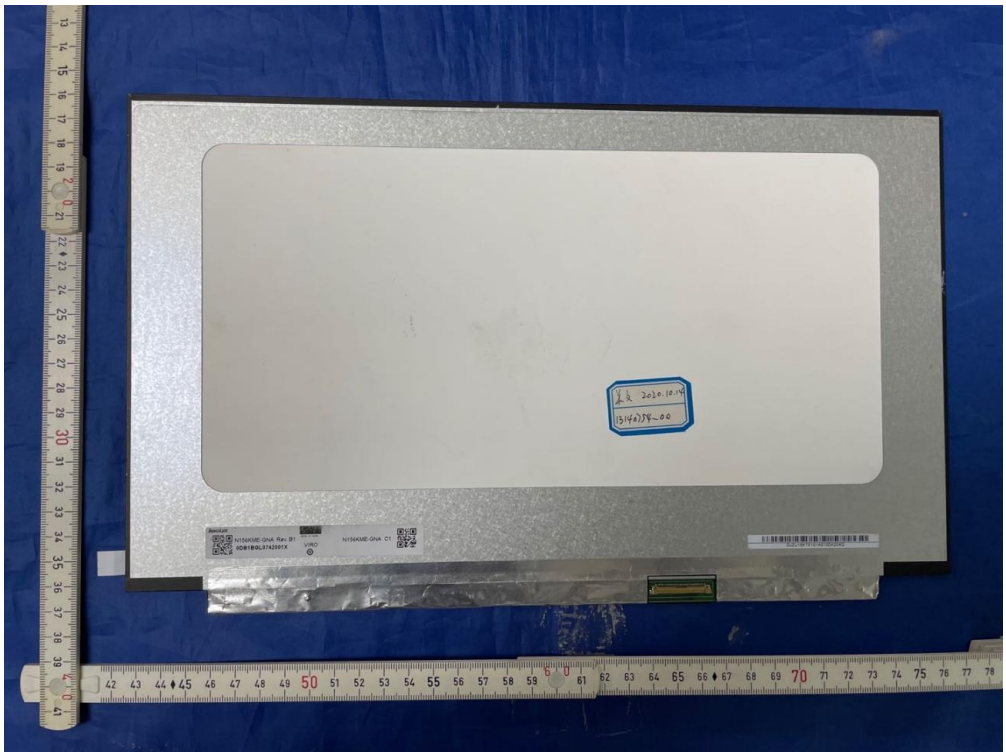

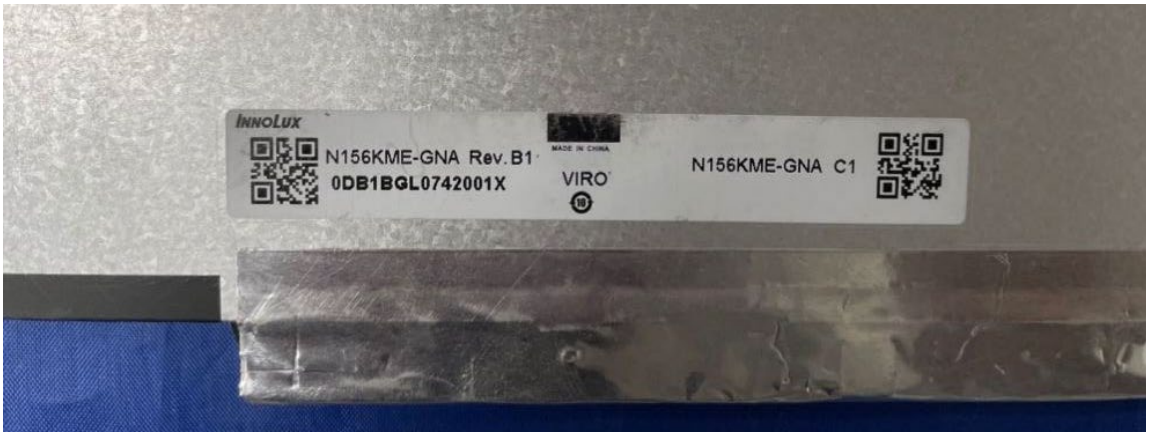
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MADE IN CHINA
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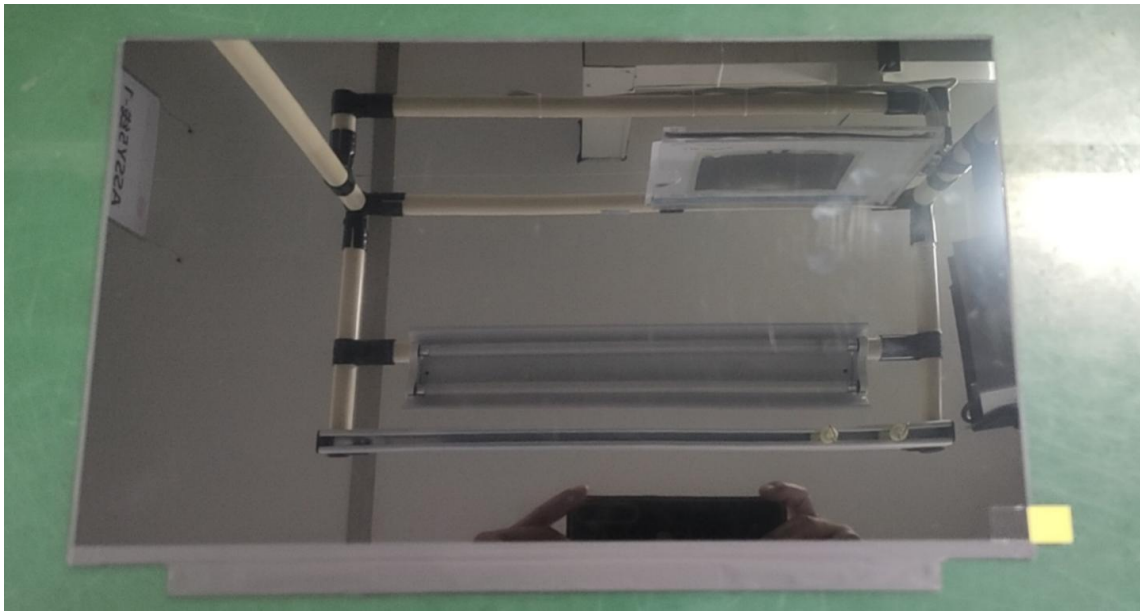

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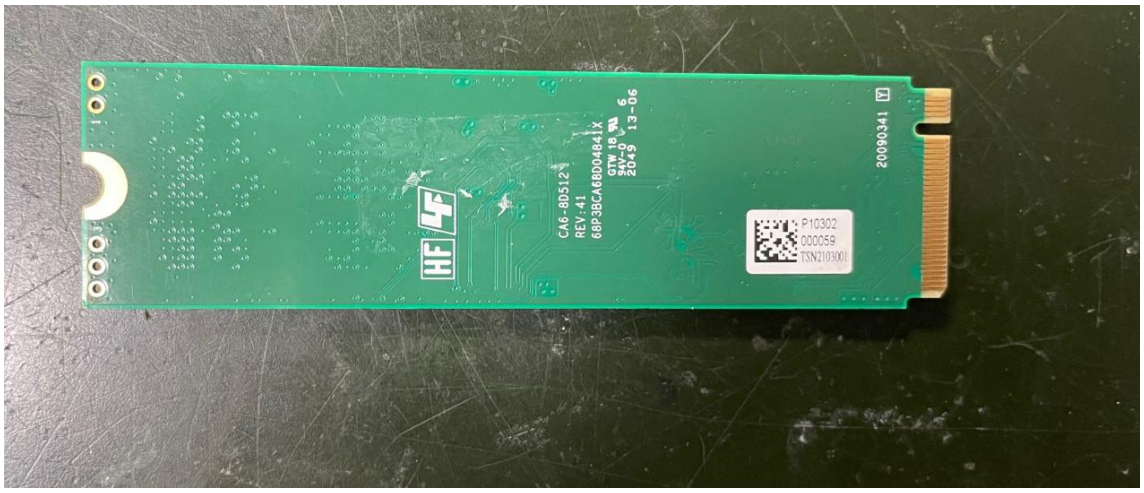
SOLID STATE STORAGE TECHNOLOGY CORPORATION
Model / 型號: CA6-8D512
Solid State Drive / 固態硬碟
Power / 額定電壓：+3.3V
S/N: 0021114Y001B
P/N: 3C07140299
Capacity: 512GB
F/W: ER20901
03/18/2021
EUI: 38F60156-3075233B
R-R-PQX-CA6-8D2048
CAN ICES-3(B)/ NMB-3(B)
https://www.ssstc.com
PSID:
MJST161V-77NU7FLQ-
PQ1C48LH-19XHGNAN
WARRANTY VOID IF LABEL REMOVED
UK/EU Contacts:
KIOXIA Europe GmbH, Branch Office UK
31 Chertsey Street, Guildford, GU1 4HD, United Kingdom
KIOXIA Europe GmbH
Hansaallee 181, 40549 Düsseldorf, Germany
E205203
D3D385
RoHS
MADE IN TAIWAN(台灣製造) 7224000505H-A MR-MXL-05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SAMSUNG ELECTRONICS CO., LTD.
www.samsung.com/semiconductor
CAN ICES-3 (B)/NMB-3(B)
WARRANTY VOID IF REMOVED

SAMSUNG
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